

Ultra-Low Power Operational Amplifier

Features

- SC70 Packaging
- 400 kHz Gain-Bandwidth Product
- 650 kHz, -3dB Bandwidth
- 4.6 µA Supply Current
- Rail-to-Rail Output
- Ground Sensing at Input (Common Mode to GND)
- Drives Large Capacitive Loads (1000 pF)
- Unity Gain Stable

Applications

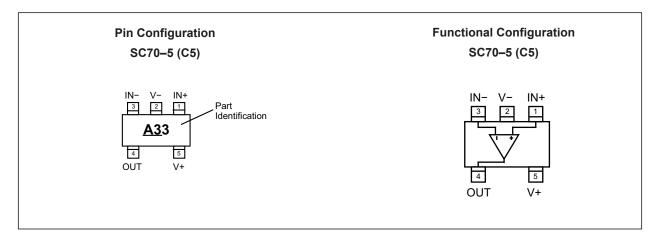
- · Handheld Electronics
- Laptop Computers
- Tablets
- Mobile Phones
- Consumer Electronics

Package Type

General Description

The MIC861 is a rail-to-rail output, input common-mode to ground, operational amplifier in SC70 packaging. The MIC861 provides a 400 kHz gain-bandwidth product while consuming an incredibly low 4.6 μ A supply current.

The SC70 packaging achieves significant board space savings over devices packaged in SOT-23 or MSOP-8 packaging. The SC70 occupies approximately half the board area of a SOT-23 package.



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage (V _{V+} to V _{V-})	+6.0V
Differential Input Voltage (V _{IN+} to V _{IN-})	
Input Voltage (V _{IN+} , V _{IN})	
Output Short-Circuit Current Duration	Indefinite
ESD Rating	
5	

Operating Ratings ‡

Supply Voltage (V+ to V-)	.+2.43V to +5.25V
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† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ Notice: The device is not guaranteed to function outside the operating ratings.

Note 1: Devices are ESD sensitive. Handling precautions are recommended. Human body model, 1.5 k Ω in series with 100 pF. Pin 4 is ESD sensitive.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V+ = +2.7V, V- = 0V V _{CM} = V+/2; R _L = 500 k Ω to V+/2; T _A = 25°C, unless otherwise	
noted. (Note 2).	

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Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions	
Input Offset Voltage		-10	2	10	mV	$-40^{\circ}C \le T_{A} \le +85^{\circ}C \text{ (Note 1)}$	
Input Offset Voltage Temperature Coefficient	V _{OS}	—	15	_	μV/°C	_	
Input Bias Current	Ι _Β		20		pА	—	
Input Offset Current	I _{OS}	—	10	—	pА	—	
Input Voltage Range	V _{CM}	—	1.8	—	V	CMRR >60 dB	
Common-Mode Rejection Ratio	CMRR	45	77	_	dB	$0 < V_{CM} < 1.35V, -40^{\circ}C \le T_{A} \le +85^{\circ}C$	
Power Supply Rejection Ratio	PSRR	50	83	_	dB	Supply voltage change of 3V, -40° C $\leq T_{A} \leq +85^{\circ}$ C	
Large-Signal		60	74	_	dB	$\label{eq:RL} \begin{split} R_L &= 100 \; k\Omega, V_OUT = 2V_PP, \\ -40^\circC \leq T_A \leq +85^\circC \end{split}$	
Voltage Gain	A _{VOL}	73	83	—	dB	$\label{eq:RL} \begin{split} R_L &= 500 \; k\Omega, V_OUT = 2V_PP, \\ -40^\circC &\leq TA \leq +85^\circC \end{split}$	
Maximum Output		V ±2 mV	V ±0.7 mV	_	V		
Voltage Swing	V _{OUT}	—	V ±0.2 mV	V ±2 mV		−R _L = 500 kΩ, –40°C ≤ T _A ≤ +85°	
Gain-Bandwidth Product	GBWP	—	350	—	kHz	R_L = 200 kΩ, C_L = 2 pF, V_{OUT} = 0	
–3 dB Bandwidth	B _W	—	500		kHz	A_V = 1, C_L = 2 pF, R_L = 1 M Ω	
Slew Rate	S _R		0.12		V/µs	$A_V = 1, C_L = 2 \text{ pF}, R_L = 1 \text{ M}\Omega$	
Short-Circuit Output	I _{SC}	_	6		mA	Source	
Current	_		5		mA	Sink	
Supply Current	I _S		4.2	9	μA	No load, $-40^{\circ}C \le T_A \le +85^{\circ}$	

ELECTRICAL CHARACTERISTICS (SINGLE SUPPLY)

Electrical Characteristics: V+ = +5V, V- = 0V, V_{CM} = V+/2; R_L = 500 k Ω to V+/2; T_A = 25°C, T_A = T_J ; unless otherwise noted (Note 2).

otherwise noted (Not	te 2).						
Parameters	Symbol	Min.	Тур.	Max.	Units	Conditions	
Input Offset Voltage		-10	2	10	mV	–40°C ≤ T _A ≤ +85°C (Note 1)	
Input Offset Voltage Temperature Coefficient	V _{OS}	_	15	_	μV/°C	_	
Input Bias Current	I _B	—	20	_	pА	—	
Input Offset Current	I _{OS}	—	10	_	pА	—	
Input Voltage Range	V _{CM}	—	4.2	_	V	CMRR >60 dB	
Common-Mode Rejection Ratio	CMRR	60	80	_	dB	$0 < V_{CM} < 3.5V, -40^{\circ}C \le T_{A} \le +85^{\circ}C$	
Power Supply Rejection Ratio	PSRR	45	85		dB	Supply voltage change of 1V, $-40^{\circ}C \le T_{A} \le +85^{\circ}C$	
Large-Signal Voltage Gain	A _{VOL}	60	76	_	dB	R_L = 100 kΩ, V _{OUT} = 4V _{PP} , -40°C ≤ TA ≤ +85°C	
		68	83		dB	$R_L = 500 k\Omega$, $V_{OUT} = 4V_{PP}$, -40°C ≤ TA ≤ +85°C	
Maximum Output	M	V ±2 mV	V ±0.7 mV		V	- R _L = 500 kΩ, –40°C ≤ T _A ≤ +85°C	
Voltage Swing	V _{OUT}		V ±0.7 mV	V ±2 mV	V		
Gain-Bandwidth Product	GBWP	_	400		kHz	R_L = 200 kΩ, C_L = 2 pF, V_{OUT} = 0	
–3 dB Bandwidth	B _W		650	_	kHz	$A_V = 1, C_L = 2 \text{ pF}, R_L = 1 \text{ M}\Omega$	
Slew Rate	S _R		0.12		V/µs	$A_V = 1, C_L = 2 \text{ pF}, R_L = 1 \text{ M}\Omega$	
Short-Circuit Output		10	24	_	mA	Source, $-40^{\circ}C \le T_A \le +85^{\circ}C$	
Current	I _{SC}	10	24	_	mA	Sink, $-40^{\circ}C \le T_A \le +85^{\circ}C$	
Supply Current	ا _S		4.6	9	μA	No load, $-40^{\circ}C \le T_A \le +85^{\circ}$	

Note 1: The offset voltage distribution is centered around 0V. The typical offset number shown is equal to the standard deviation of the voltage offset distribution.

2: Specification for packaged product only. Exceeding the maximum differential input voltage will damage the input stage and degrade performance (in particular, input bias will likely increase).

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions			
Temperature Ranges									
Storage Temperature	Ts	_	_	150	°C	—			
Ambient Temperature Range	T _A	-40	_	+85	°C	—			
Lead Temperature	_	_	_	260	°C	Soldering, 5s			
Package Thermal Resistance									
Thermal Resistance SC70	θ _{JA}	_	450	_	°C/W	_			

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +85°C rating. Sustained junction temperatures above +85°C can impact the device reliability.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

DC Typical Characteristics:

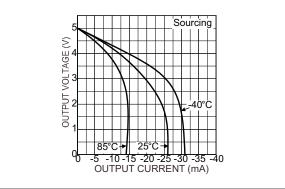


FIGURE 2-1: Output Voltage vs. Output Current.

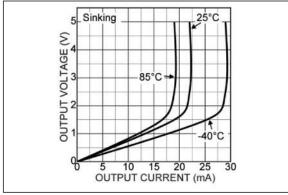


FIGURE 2-2: Output Voltage vs. Output Current.

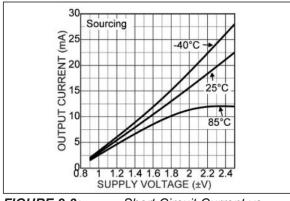


FIGURE 2-3: Short Circuit Current vs. Supply Voltage.

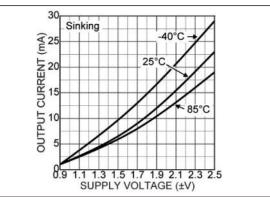


FIGURE 2-4: Short Circuit Current vs. Supply Voltage.

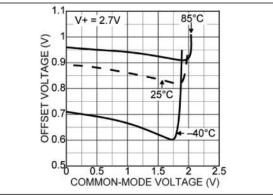


FIGURE 2-5: Offset Voltage vs. Common-Mode Voltage.

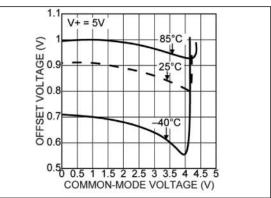


FIGURE 2-6: Offset Voltage vs. Common-Mode Voltage.

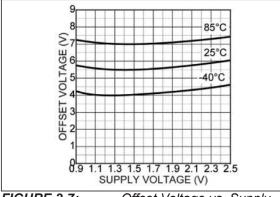


FIGURE 2-7: Offset Voltage vs. Supply Voltage.

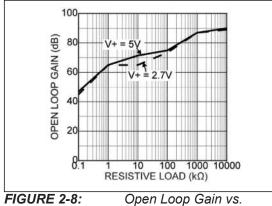


FIGURE 2-8: Resistive Load.

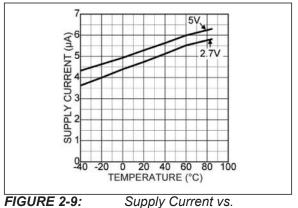


FIGURE 2-9: Temperature.

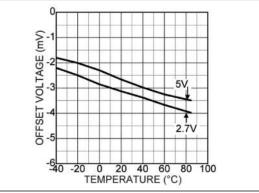


FIGURE 2-10: Offset Voltage vs. Temperature.

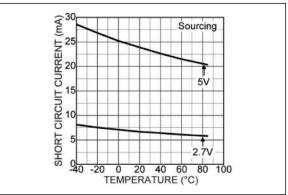


FIGURE 2-11: Short Circuit Current vs. Temperature.

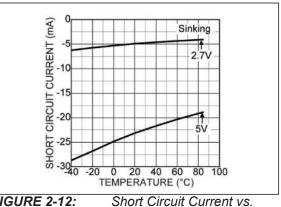


FIGURE 2-12: Temperature.

AC Typical Characteristics:

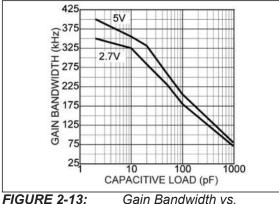


FIGURE 2-13: Gain Bandwidth vs. Capacitive Load.

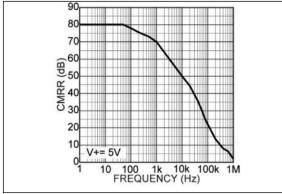
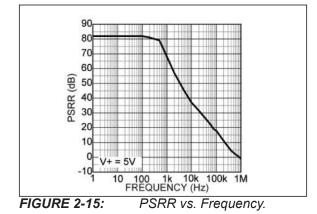
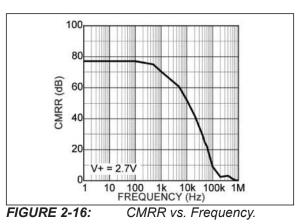


FIGURE 2-14: CMRR vs. Frequency.





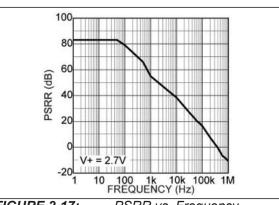


FIGURE 2-17: PSRR vs. Frequency.

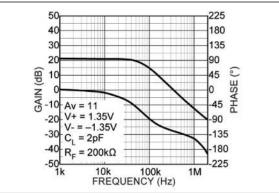


FIGURE 2-18: Gain Bandwidth and Phase Margin.

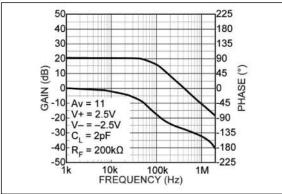
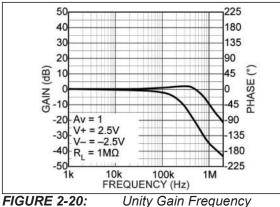


FIGURE 2-19: Gain Bandwidth and Phase Margin.



Response.

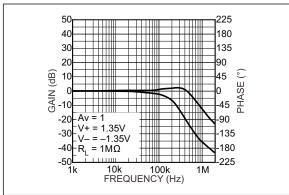
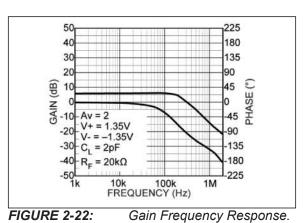


FIGURE 2-21: Unity Gain Frequency Response.



50 225 180 40 30 135 20 90 PHASE (°) GAIN (dB) 10 45 0 45 = 2 -10 = 25V90 -20 -2.5V -30 135 = 2pF C, 180 -40 = 20kΩ 225 -5 10k 100k FREQUENCY (Hz) 1M

FIGURE 2-23: Gain Bandwidth and Phase Margin.

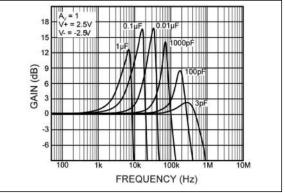
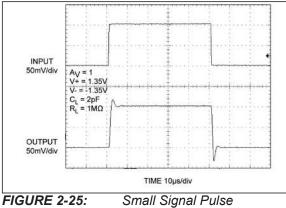


FIGURE 2-24: Closed-Loop Unity Gain Frequency Response.



Response (See Figure 3-3).

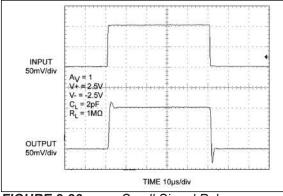
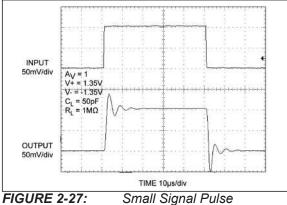


FIGURE 2-26: Small Signal Pulse Response (See Figure 3-3).



Response (See Figure 3-3).

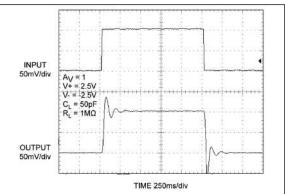


FIGURE 2-28: Small Signal Pulse Response (See Figure 3-3).

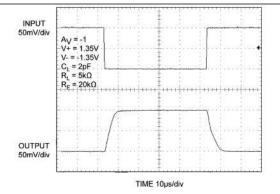


FIGURE 2-29: Small Signal Pulse Response (See Figure 3-4).

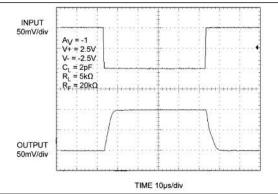


FIGURE 2-30: Small Signal Pulse Response (See Figure 3-4).

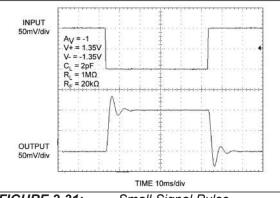
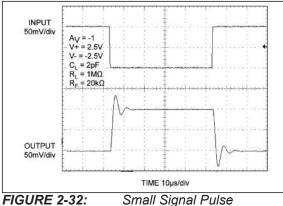
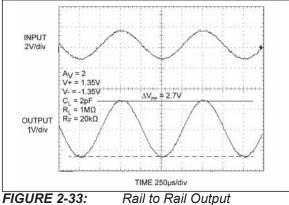


FIGURE 2-31: Small Signal Pulse Response (See Figure 3-4).



Response (See Figure 3-4).



Operation.

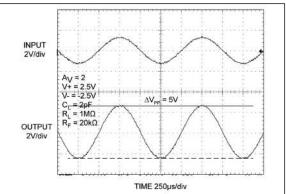


FIGURE 2-34: Rail to Rail Output Operation.

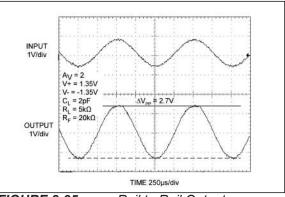
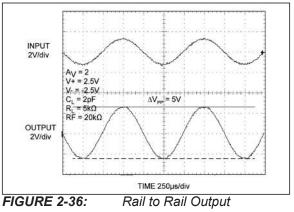


FIGURE 2-35: Rail to Rail Output Operation.



Operation.

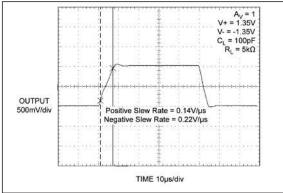


FIGURE 2-37: Large Signal Pulse Response (See Figure 3-3).

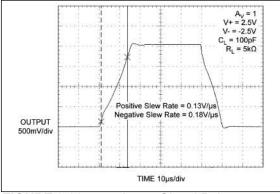


FIGURE 2-38: Large Signal Pulse Response (See Figure 3-3).

3.0 TEST CIRCUITS

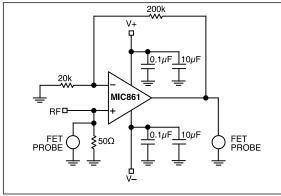
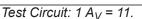
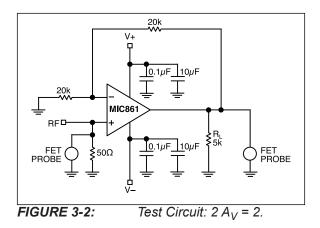
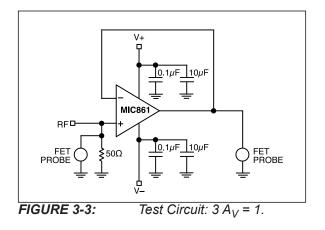


FIGURE 3-1:







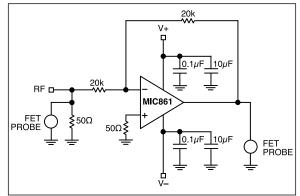


FIGURE 3-4: Test

Test Circuit: $4 A_V = -1$.

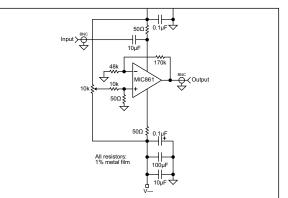


FIGURE 3-5: Test Circuit: 5 Positive Power Supply Rejection Ratio Measurement.

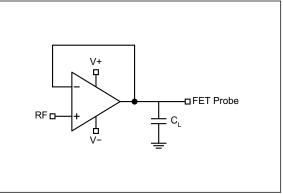


FIGURE 3-6: Test Circuit: 6 Closed-Loop Unity Gain Frequency Response Measurement.

4.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 4-1.

TABLE 4-1: PIN FUNCTION TABLE

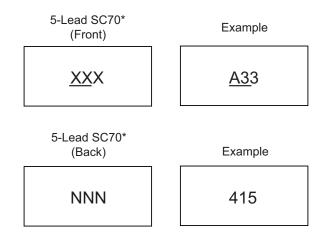
Pin Number	Symbol	Description
1	IN+	Non-inverting input.
2	V–	Negative power supply connection. Connect a 10 μF and 0.1 μF capacitor in parallel to this pin for power supply bypassing.
3	IN–	Inverting Input.
4	OUT	Output of operational amplifier.
5	V+	Positive power supply input. Connect a 10 μF and 0.1 μF capacitor in parallel to this pin for power supply bypassing.

5.0 APPLICATION INFORMATION

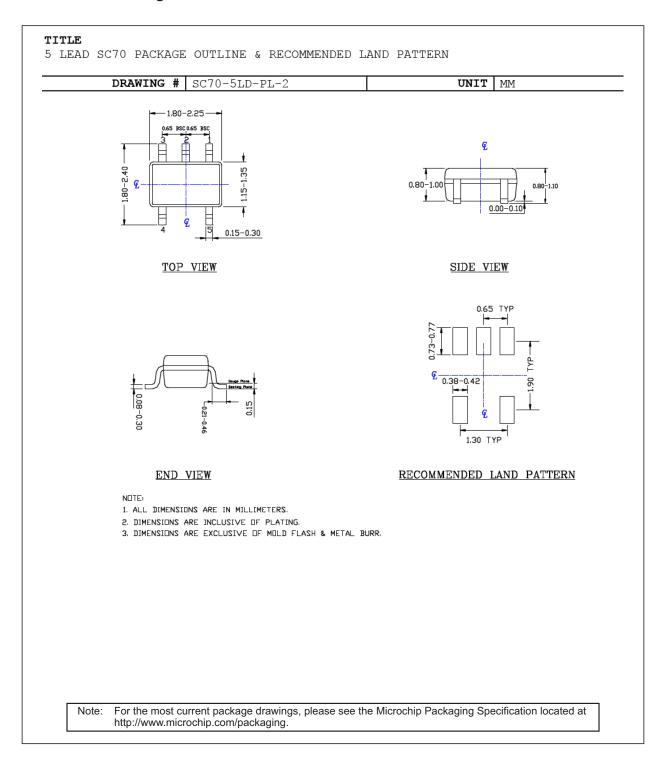
Regular supply bypassing techniques are recommended. A 10 μ F capacitor in parallel with a 0.1 μ F capacitor on both the positive and negative supplies is ideal. For best performance, all bypassing capacitors should be located as close to the op amp as possible and all capacitors should be low equivalent series inductance (ESL) and equivalent series resistance (ESR). Surface-mount ceramic capacitors are ideal.

6.0 PACKAGING INFORMATION

6.1 Package Marking Information



Legend	Y YY WW NNN @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
	be carried	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information. Package may or may not include ate logo.
	Underbar	(_) and/or Overbar (⁻) symbol may not be to scale.



5-Lead SC70 Package Outline and Recommended Land Pattern

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (July 2020)

- Converted Micrel document MIC861 to Microchip data sheet template DS20006347A.
- Minor text changes throughout.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

	TNO	V 107	1	Examp	oles:	
	TNO. vice Ten MIC861:	X X -XX perature Package Media Type Ultra-Low Power Operational Amplifier		a) M	IIC861YC5-TR:	Op Amp, –40°C to +85°C Junction Temperature Range, 5-Lead SC70 Package, 3,000/Reel
Femperature:	Y =	–40°C to +85°C	'	Note 1:	catalog part num used for ordering	dentifier only appears in the ber description. This identifier is g purposes and is not printed on age. Check with your Microchip
Package:	C5 =	5-Lead SC70				package availability with the
Media Type:	TR =	3.000/Reel				

NOTES:

Note the following details of the code protection feature on Microchip devices:

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Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

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